

Category: MOSFET CIRCUIT IDEAS FOR DESIGNERS

Schematic no. fet_11102.0

Basic EPAD® MOSFET Connection with Current Source Drive

Description

This circuit shows a basic diode–connected MOSFET connection driven by a constant current source. The drain terminal is shorted to the gate terminal. When connected in this manner, this circuit produces an output voltage Vo. The drain current Ids that flows through the MOSFET increases exponentially with increases of Vo, with Ids vs. Vo characteristics similar to that of a forward biased diode. Hence the term "diode-connected" configuration. This type of circuit is very useful to clamp or control the output to a certain voltage level and not allowing Vo to increase rapidly with current increase. When a constant current of 68μ A is applied, the resultant output voltage tend to be temperature stable. This results in a voltage about 55mV above threshold voltage of the EPAD MOSFET. At other voltage or current levels, the tempco changes from positive to negative as a function of drain currents. By selecting and setting a constant current source level, a voltage output with a certain positive, zero or negative temperature coefficient can be maintained.

For full schematic diagram and notes, please register and login at aldinc.com